

UPSD3233B-40T6 STMicroelectronics Product Details





Images are for reference See Product Specification













Part Number: UPSD3233B-40T6

EOLSEMI Part: UPSD3233B-40T6-29229

Category: MCU

Manufacturer: STMicroelectronics

Applications: ■Aerospace & defense ■Test & measurement

■Automotive
■Communications equipment

Description: IC MCU 8BIT 160KB FLASH 52TQFP

Lead free / RoHS Compliant **RoHS:**

Stock Category: In stock

Stock Resource: Franchised Distributor

Warranty: 1 Year Guarantee » Learn More

EDA/CAD Models: <u>UPSD3233B-40T6</u> PCB Footprint and Symbol

Delivery:

Payment: PayPal VISA CO T/T WEMENWU

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K4H561638F-UCB3 - Samsung Semiconductor - DRAM

SDRAM, DDR, 16M x 16, 66 Pin, Plastic, TSSOP

K4M561633G-BN75 - Samsung Electro-Mechanics - DRAM

SYNCHRONOUS DRAM, 16MX16, 5.4NS, CMOS, PBGA54

<u>K4P4G324EB-AGC1</u> - <u>Samsung Semiconductor</u> - <u>DRAM</u>

DRAM Chip Mobile LPDDR2 SDR 4G-Bit 128Mx32 1.2V 168-Pin FBGA - Trays (Alt: KADAC324ER, ACC1000)

K4P8G304EB-FGC1 - Samsung Electro-Mechanics - DRAM

MOBILE DDR2-S4 SDRAM MEMORY, 1GB X 32, 400MHZ, FBGA134

K4S161622D-TC80 - Samsung Electro-Mechanics - DRAM

SDRAM, 1M x 16, 50 Pin, Plastic, TSOP

K4S281632F-UC75 - Samsung Electronics Co. Ltd - DRAM

SDRAM, 8M x 16, 54 Pin, Plastic, TSOP

K4T1G164QF-BCE6 - Samsung Electro-Mechanics - DRAM

IC,SDRAM,DDR,8X8MX16,CMOS,BGA,84PIN,PLASTIC

<u>K4T1G164QE-HPE6</u> - <u>Samsung Electro-Mechanics</u> - <u>DRAM</u>

DDR DRAM, 64MX16, 0.45NS, CMOS, PBGA84

<u>K4T51163QJ-BCE7</u> - <u>Samsung Electronics Co. Ltd</u> - <u>DRAM</u>

32M X 16 DDR DRAM, 0.4 ns, PBGA84

K4T51163QG-HCE6 - Samsung Semiconductor - DRAM

32M X 16 DDR DRAM, 0.45 ns, PBGA84

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